

μPA503CT

P-CHANNEL MOSFET FOR SWITCHING

R07DS1279EJ0200 Rev.2.00 Jul 08, 2015

Description

The μ PA503CT, P-channel vertical type MOSFET designed for general-purpose switch, is a device which can be driven directly by a 4.5 V power source.

Features

- Two MOSFET circuits (Two source common)
- Directly driven by a 4.5 V power source.
- Low on-state resistance

 $R_{DS(on)1}$ = 2.7 Ω MAX. (V_{GS} = -10 V, I_D = -100 mA)

 $R_{DS(on)2} = 3.2 \Omega MAX. (V_{GS} = -4.5 V, I_{D} = -50 mA)$

Ordering Information

Part Number	Lead Plating	Packing	Package	
µPA503CT-T1-A/AT	-A:Sn-Bi, -AT:Pure Sn	3000p/Reel	SC-74A (5pMM)	

Remark "-A/AT" indicates Pb-free. This product does not contain Pb in external electrode and other parts.

Marking UF

Absolute Maximum Ratings (TA = 25°C)

Drain to Source Voltage (Vss = 0 V)	VDSS	-60	V
Gate to Source Voltage (V _{DS} = 0 V)	Vgss	∓20	V
Drain Current (DC)	I _{D(DC)}	∓100	mA
Drain Current (pulse) Note	ID(pulse)	∓200	mA
Total Power Dissipation	Рт	300 (Total)	mW
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	-55 to +150	°C

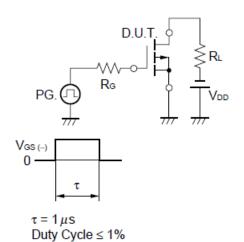
Note PW \leq 10 μ s, Duty Cycle \leq 1%

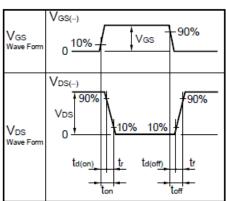
Electrical Characteristics (T_A = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-1	μА
Gate Leakage Current	Igss	V _{GS} = ∓20 V, V _{DS} = 0 V			∓10	μA
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	-1.0		-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -100 mA	150			mS
Drain to Source On-state Resistance Note	RDS(on)1	V _{GS} = -10 V, I _D = -100 mA		1.8	2.7	Ω
	RDS(on)2	V _{GS} = -4.5 V, I _D = -50 mA		2.0	3.2	Ω
Input Capacitance	Ciss	V _{DS} = -10 V,		9		pF
Output Capacitance	Coss	V _{GS} = 0 V,		7		pF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		2		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = -10 V,		75		ns
Rise Time	tr	I _D = -200 mA,		110		ns
Turn-off Delay Time	td(off)	V _{GS} = -10 V,		900		ns
Fall Time	tf	R _G = 10 Ω		400		ns
Total Gate Charge	Q _G	I _D = -200 mA, V _{DD} = -25 V, V _{GS} = -10 V		2.2		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	I _F = -200 mA, V _{GS} = 0 V		0.86		V

Note Pulsed

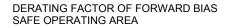
Test Circuit Switching Time

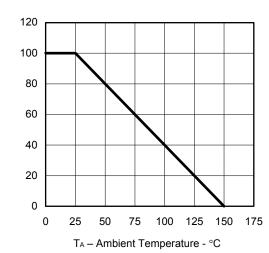




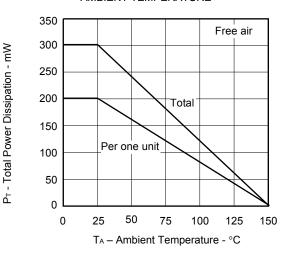
dT - Percentage of Rated Power - %

Typical Characteristics (T_A = 25°C)

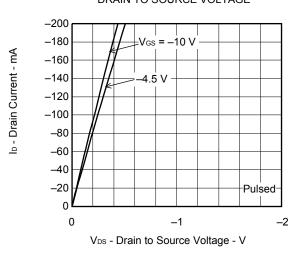




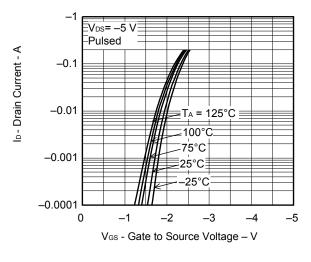
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE



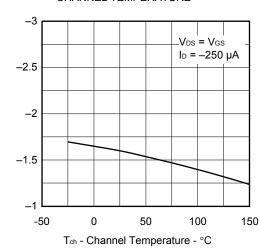
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



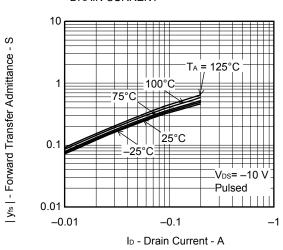
FORWARD TRANSFER CHARACTERISTICS



GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



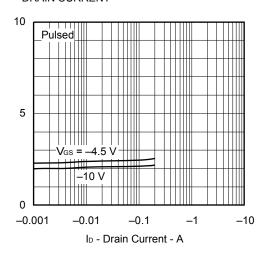
VGS(Off) - Gate Cut-off Voltage - V

 $\mathsf{Rbs}_{(\text{on)}}$ - Drain to Source On-state Resistance - Ω

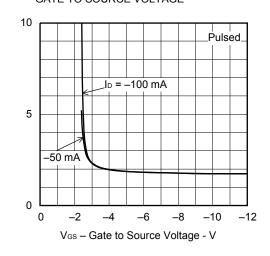
 $\mathsf{Rbs}_{(\text{on})}\text{-}$ Drain to Source On-state Resistance - Ω

td(on), tr, td(off), tr - Switching Time - ns

DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT

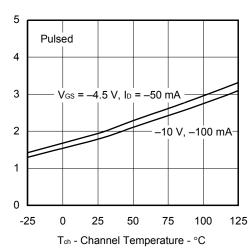


DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE

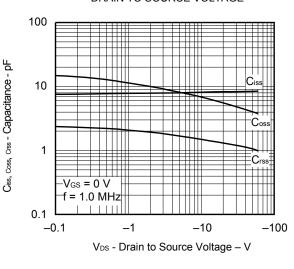


 $\mathsf{R}_{\mathsf{DS}(\mathsf{on})}$ - Drain to Source On-state Resistance - Ω

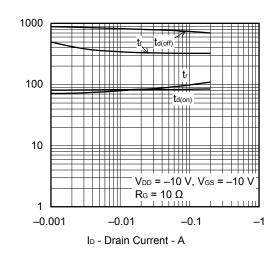
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



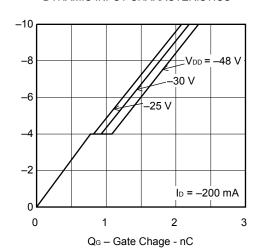
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS

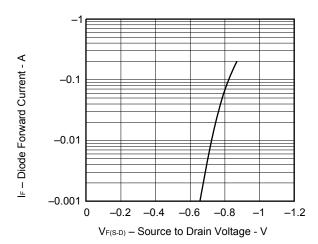


DYNAMIC INPUT CHARACTERISTICS

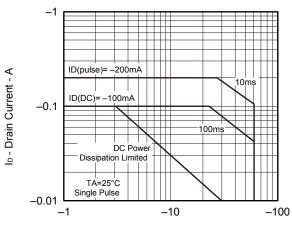


Ves - Gate to Source Voltage - V

SOURCE TO DRAIN DIODE FORWARD VOLTAGE



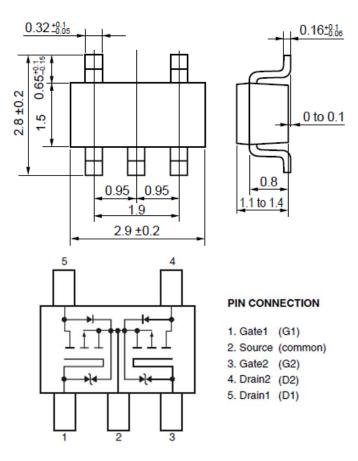
FORWARD BIAS SAFE OPERATING AREA



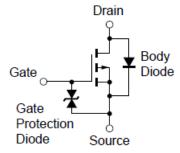
V_{DS} - Drain to Source Voltage - V

Package Drawings (Unit: mm)

SC-74A (5pMM)



Equivalent Circuit



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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		Description		
Rev.	Date	Page	Summary	
1.00	Sep , 2013	_	First Edition Issued	
2.00	Jun, 2015	3, 4, 5	Changed all graphs	
		3	Added FORWARD BIAS SAFE OPERATING AREA	

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